

MODEL MM002052P50B
20~520MHz
100 WATTS
WIDE BAND POWER RF AMPLIFIER

Advantages:

- Operating Frequency :20~520MHz
- Power Gain:50dB Typical
- Psat:100W Typical
- Supply Voltage:+28V
- 50 Ohms Input and Output Matched

ELECTRICAL SPECIFICATIONS @ +28.0VDC, 25°C, 50Ω

Parameter	Symbol	Min	Typ	Max	Units
Operating Frequency	BW	20		520	MHz
RF Output Power @Pin=0dBm	PSAT		100		Watt
Power Gain	Gp		50		dB
Power Gain Flatness	Δ Gp		±2		dB
Input Return Loss	S11			-10	dB
Harmonics @80W	H		-10		dBc
Spurious Signals	Spur		-60		dBc
In/Output Impedance	Impedance		50		Ω
Operating Voltage	VDC	24	28	32	Volt
DC Current @100W	IDD		9		Amp

MECHANICAL SPECIFICATIONS

Parameter	Value	Units	Notes
Dimensions	150x90x25[5.91x3.54x0.98]	mm [inch]	Maximum
Weight	1.2 [2.64]	kg [lbs]	Maximum
RF Connectors Input	SMA, Female		
RF Connectors Output	SMA, Female		
DC Interface Connector	D-Sub 9-Pin, Male		
Cooling	External Heatsink Required(Not Supplied)		

ENVIRONMENTAL CHARACTERISTICS (Design to Meet)

Parameter	Minimum	Typical	Maximum	Units	Notes
Operating Temperature	-40		60	°C	
Non-operating Temperature	-45		85	°C	Storage
Relative Humidity (non-condensing)			95	%	

ABSOLUTE MAXIMUM RATING

Input RF drive level without damage	+10 dBm (Max)
Load VSWR @ POUT=50W	∞ @ all load phase & amplitude for duration of 1 minute; 3:1 @ all load phase & amplitude continuous.
Over Temperature	85°C @ heatsink [restored @ 60°C]

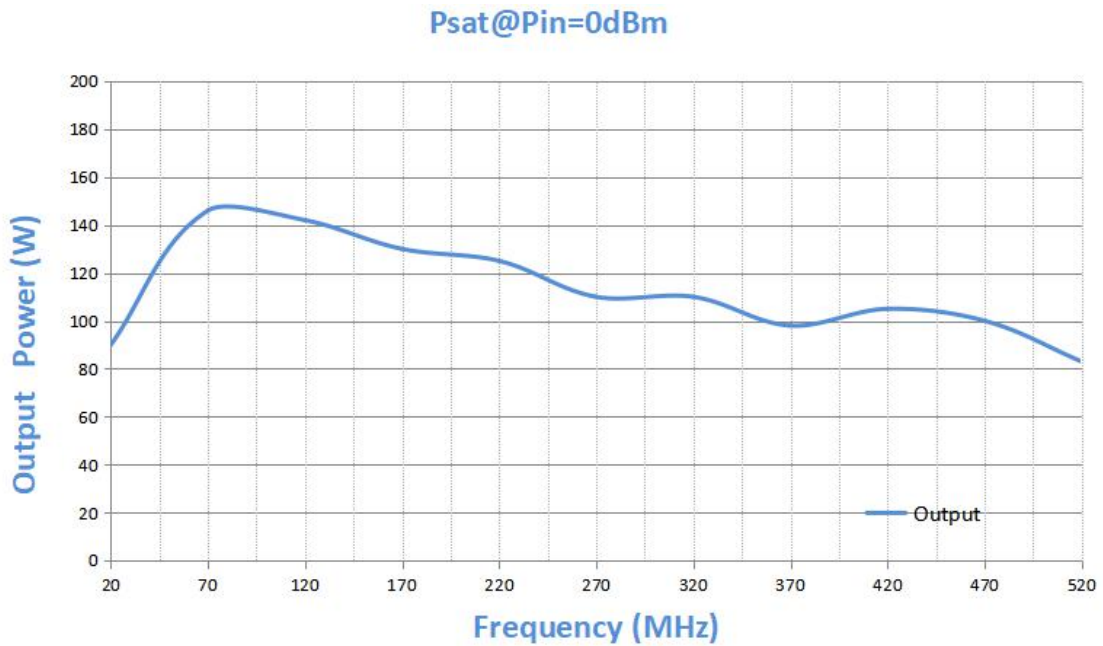
POWER INTERFACE CONNECTOR

Male D-Sub is on the housing

Pin #	Name	Specifications
1	SHUTDOWN	Amplifier Disable: TTL Logic High (3.3V~5V) (Internally Pulled-Low)
2	TEMP SENSE	Analog voltage relative to Module's Temperature @ 0.5V+10 mV/°C
3	CURRENT SENSE	Analog voltage relative to IDD @ 100mV per Ampere
4	VDD	28VDC
5	VDD	28VDC
6	GND	Ground
7	GND	Ground
8	GND	Ground
9	VDD	28VDC

TYPICAL PERFORMANCE PLOTS (FOR REFERENCE ONLY)

Output Power (Normal temp. +25±3 °C)



Note: Adequate heatsink required.